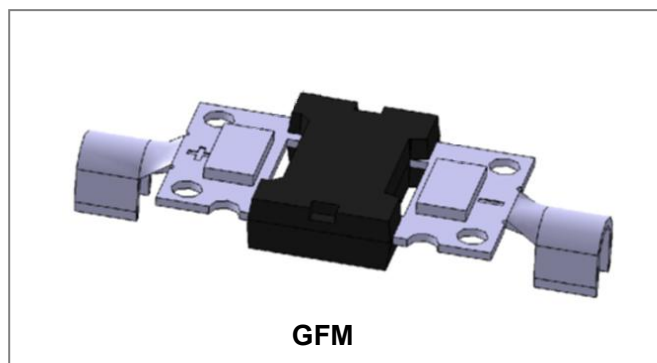


GF4045PS Power Schottky Module Bypass Diode


GFM

Features

- Schottky Barrier high diode
- Low thermal resistance
- Lower forward voltage drop, low power loss
- Isolate Package design, ideal for heat dispersion
- High forward current capability
- Excellent anti-humidity
- Low profile package
- High forward surge capability
- Terminals: Tin plated
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Mechanical Data

- Case: GFM
- High temperature soldering guaranteed
- Heated-tool welding 260°C, 10 seconds
- Marking Code: GF4045PS

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	45	V
Average Rectified Forward Current	$I_F (AV)$	$T_c = 109^\circ\text{C}$, In DC	50	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine pulse	350	A

Electrical Characteristics

Characteristics	Symbol	Condition	Typ.	Max.	Units
Peak Forward Voltage	V_{F1}	@40A, Pulse, $T_J = 25^\circ\text{C}$	0.52	0.55	V
Peak Reverse Current	I_{R1}	@ V_R = rated V_R , $T_J = 25^\circ\text{C}$	0.08	0.50	mA
	I_{R2}	@ V_R = rated V_R , $T_J = 100^\circ\text{C}$	-	100	
Junction Capacitance	C_T	@ $V_R = 5\text{V}$, $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$	1730	-	pF

* Pulse width < 300 μs , duty cycle < 2%

Technical Data
Data Sheet N2681, Rev.-

Thermal-Mechanical Specifications

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	IN DC Forward Mode, without reverse bias, $t \leq 1$ h	-55 to +200	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	-	1.5	°C/W

Ratings and Characteristics Curves

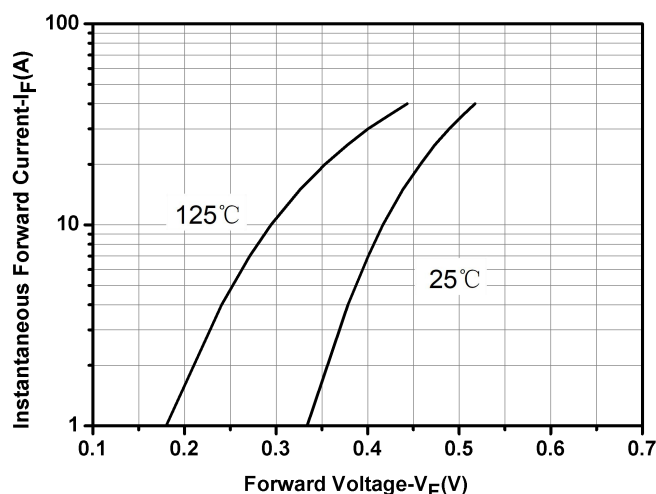


Fig.1-Typical Forward Voltage Characteristics

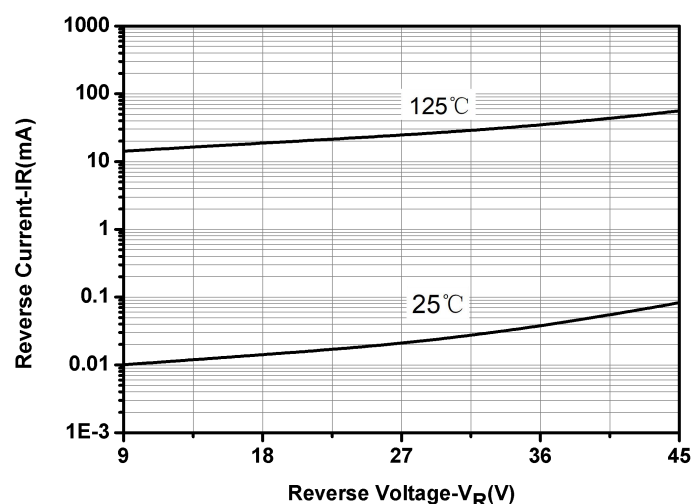


Fig.2-Typical Reverse Characteristics

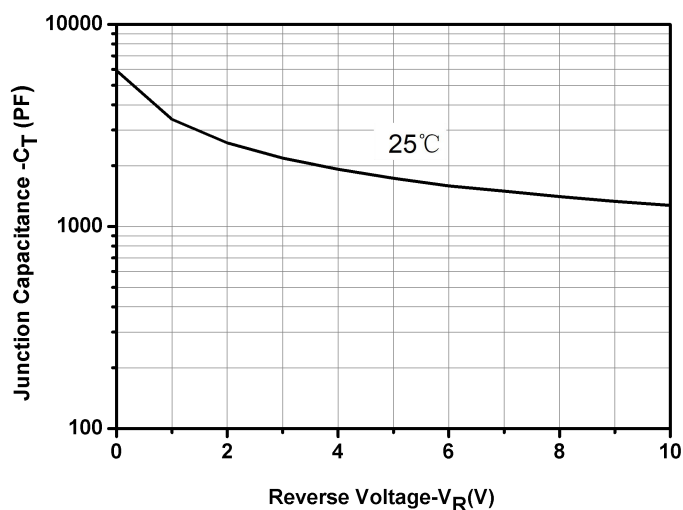
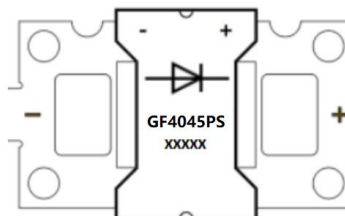


Fig.3-Capacitance vs. Reverse Voltage

Technical Data
Data Sheet N2681, Rev.-
Ordering Information

Device	Package	Shipping
GF4045PS	GFM	30pcs / Tube

Marking Diagram


Where XXXXX is YYWWL

GF4045PS = Marking Code
 YY = Year
 WW = Week
 L = Lot Number

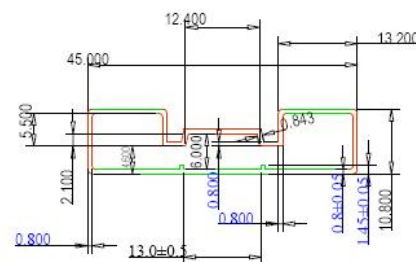
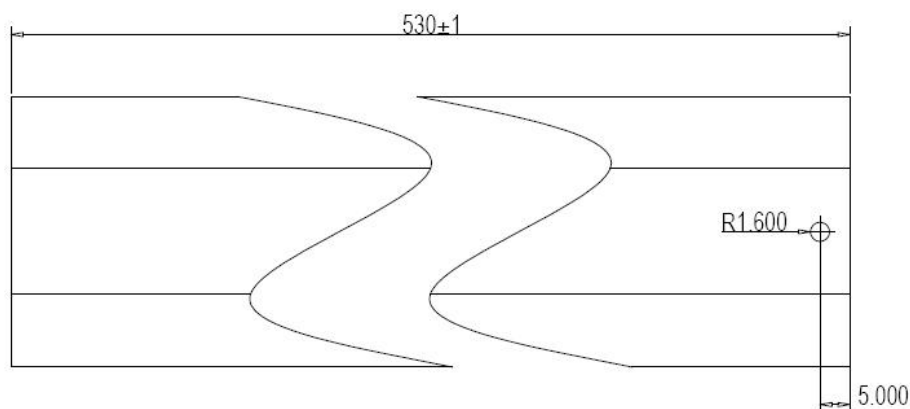
Order P/N	Terminals	Additional
GF4045PS-S1	Tin Plated	None
GF4045PS-S2	Tin Plated	Solder Paste
GF4045PS-S3	Tin Plated	Solder Block
GF4045PS-N1	Nickel Plated	None
GF4045PS-N2	Nickel Plated	Solder Paste
GF4045PS-N3	Nickel Plated	Solder Block



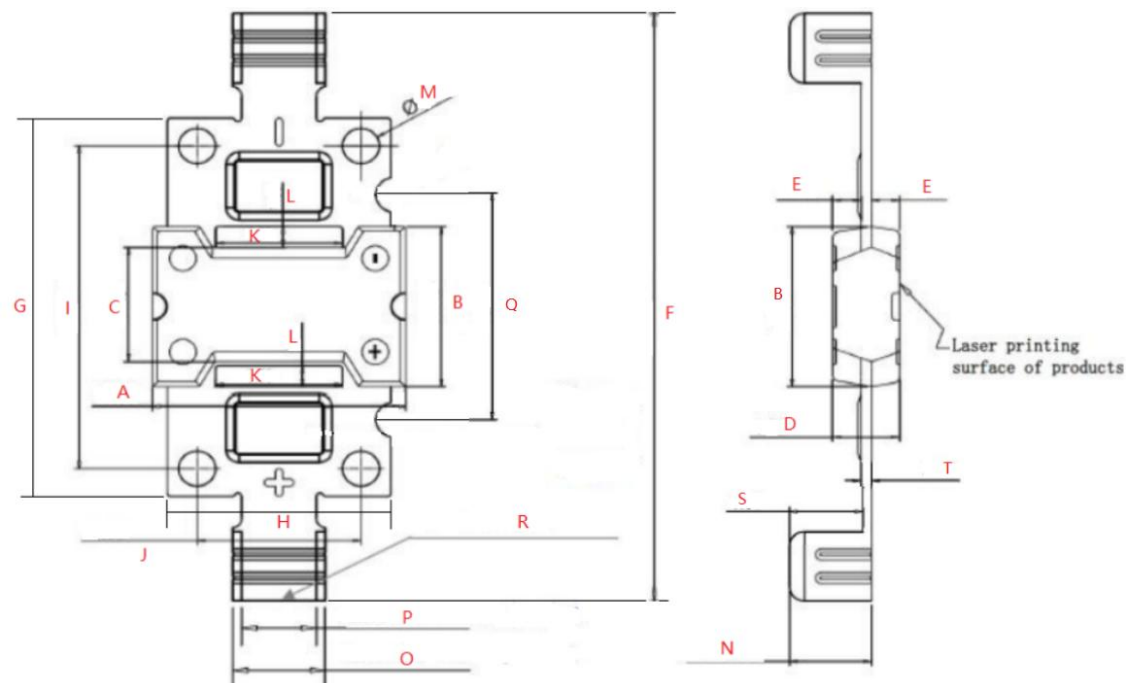
Solder Paste



Solder Block

Tube Specification GFM (Millimeters)


Mechanical Dimensions GFM (Millimeters)



Symbol	Dimensions in millimeters		
	Min.	Typical	Max
A	16.90	17.00	17.10
B	11.38	11.48	11.58
C	8.15	8.20	8.25
D	4.40	4.50	4.60
E	1.85	1.90	1.95
F	41.90	42.00	42.10
G	26.90	27.00	27.10
H	14.90	15.00	15.60
I	22.90	23.00	23.10
J	10.90	11.00	11.10
K	-	8.50	-
L	-	1.50	-
M	-	∅ 2.50	2.55
N	5.35	5.50	5.65
O	6.20	6.30	6.40
P	4.90	5.00	5.10
Q	15.95	16.00	16.05
R	2.80	2.90	3.00
S	4.75	4.80	4.85
T	0.67	0.70	0.73

Dimension H includes Burrs/cutting residuals.

Technical Data
Data Sheet N2681, Rev.-

DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Diode Solutions sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment , and safety equipment) , safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement .
- 3- In no event shall SMC Diode Solutions be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Diode Solution assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Diode Solutions be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Diode Solutions.
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Diode Solutions.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..